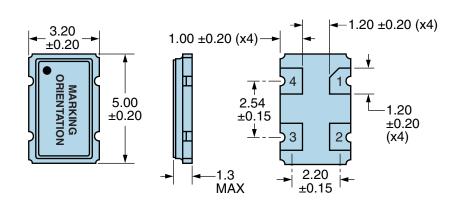


| ELECTRICAL SPECIFICAT | ELECTRICAL SPECIFICATIONS | |
|---------------------------------------|--|--|
| Nominal Frequency | 75.000MHz | |
| Frequency Tolerance/Stability | ±100ppm Maximum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range,Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Shock, and Vibration) | |
| Aging at 25°C | ±5ppm/year Maximum | |
| Operating Temperature Range | 0°C to +70°C | |
| Supply Voltage | 3.3Vdc ±0.3Vdc | |
| Input Current | 28mA Maximum (Unloaded) | |
| Output Voltage Logic High (Voh) | Vdd-0.4Vdc Minimum (IOH = -8mA) | |
| Output Voltage Logic Low (Vol) | 0.4Vdc Maximum (IOL = +8mA) | |
| Rise/Fall Time | 4nSec Maximum (Measured at 20% to 80% of waveform) | |
| Duty Cycle | 50 ±10(%) (Measured at 50% of waveform) | |
| Load Drive Capability | 15pF Maximum | |
| Output Logic Type | CMOS | |
| Pin 1 Connection | Tri-State (Disabled Output: High Impedance) | |
| Tri-State Input Voltage (Vih and Vil) | 70% of Vdd Minimum to enable output, 20% of Vdd Maximum to disable output, No Connect to enable output. | |
| Standby Current | 20μA Maximum (Pin 1 = Ground) | |
| Disable Current | 16mA Maximum (Pin 1 = Ground) | |
| Absolute Clock Jitter | ±125pSec Maximum, ±75pSec Typical | |
| One Sigma Clock Period Jitter | ±40pSec Maximum | |
| Start Up Time | 10mSec Maximum | |
| Storage Temperature Range | -55°C to +125°C | |
| | • | |

| ENVIRONMENTAL & MEC | ENVIRONMENTAL & MECHANICAL SPECIFICATIONS | |
|------------------------------|---|--|
| Fine Leak Test | MIL-STD-883, Method 1014, Condition A | |
| Gross Leak Test | MIL-STD-883, Method 1014, Condition C | |
| Mechanical Shock | MIL-STD-202, Method 213, Condition C | |
| Resistance to Soldering Heat | MIL-STD-202, Method 210 | |
| Resistance to Solvents | MIL-STD-202, Method 215 | |
| Solderability | MIL-STD-883, Method 2003 | |
| Temperature Cycling | MIL-STD-883, MEthod 1010 | |
| Vibration | MIL-STD-883, Method 2007, Condition A | |

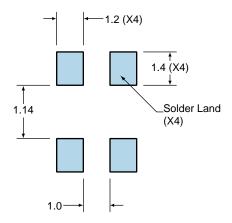
MECHANICAL DIMENSIONS (all dimensions in millimeters)



| PIN | CONNECTION |
|------|--|
| 1 | Tri-State (High Impedance) |
| 2 | Ground/Case Ground |
| 3 | Output |
| 4 | Supply Voltage |
| LINE | MARKING |
| 1 | E75.000 <i>E=Ecliptek Designator</i> |

Suggested Solder Pad Layout

All Dimensions in Millimeters



All Tolerances are ±0.1

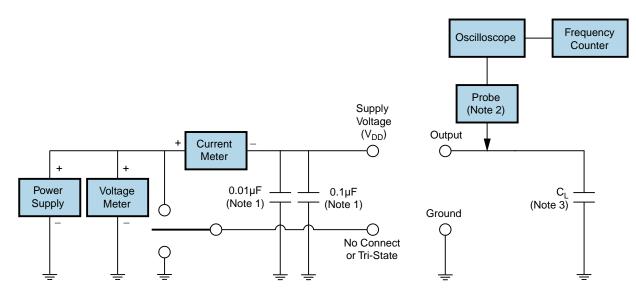




OUTPUT WAVEFORM & TIMING DIAGRAM



Test Circuit for CMOS Output



Note 1: An external 0.1μ F low frequency tantalum bypass capacitor in parallel with a 0.01μ F high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.

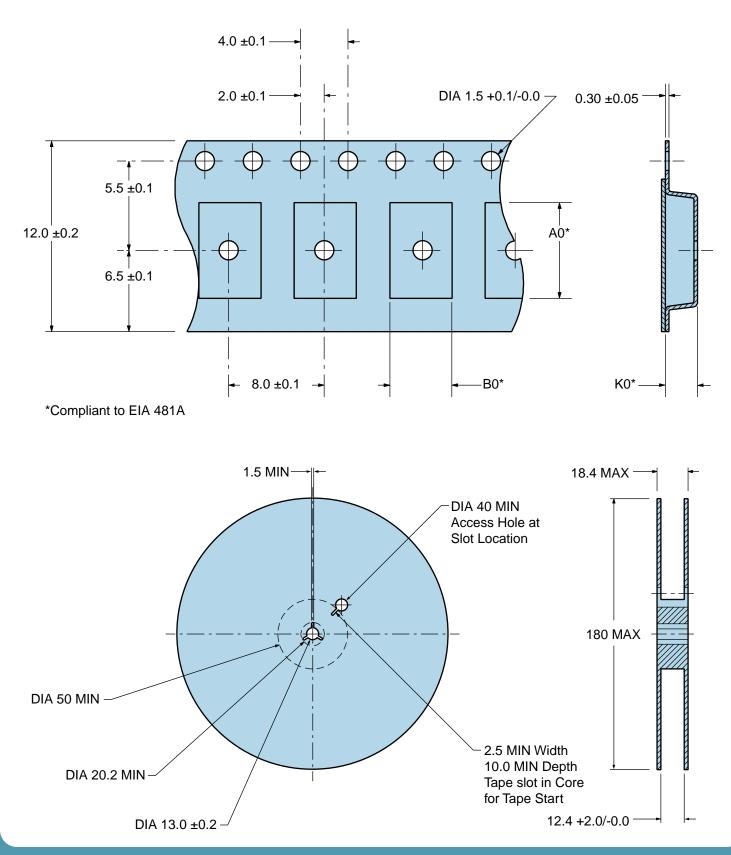
Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value \dot{C}_L includes sum of all probe and fixture capacitance.



Tape & Reel Dimensions

Quantity Per Reel: 1,000 units



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Recommended Solder Reflow Methods

EP3600TS-75.000M TR



High Temperature Infrared/Convection

| T _s MAX to T _L (Ramp-up Rate) | 3°C/second Maximum |
|---|--------------------------------------|
| Preheat | |
| - Temperature Minimum (T _s MIN) | 150°C |
| - Temperature Typical (T _s TYP) | 175°C |
| Temperature Maximum (T_s MAX) | 200°C |
| - Time (t _s MIN) | 60 - 180 Seconds |
| Ramp-up Rate (T _L to T _P) | 3°C/second Maximum |
| Time Maintained Above: | |
| - Temperature (T∟) | 217°C |
| - Time (t _L) | 60 - 150 Seconds |
| Peak Temperature (T _P) | 260°C Maximum for 10 Seconds Maximum |
| Target Peak Temperature (T _P Target) | 250°C +0/-5°C |
| Time within 5°C of actual peak (t _p) | 20 - 40 seconds |
| Ramp-down Rate | 6°C/second Maximum |
| Time 25°C to Peak Temperature (t) | 8 minutes Maximum |
| Moisture Sensitivity Level | Level 1 |
| | |



Recommended Solder Reflow Methods

EP3600TS-75.000M TR



Low Temperature Infrared/Convection 240°C

| T _s MAX to T _L (Ramp-up Rate) | 5°C/second Maximum |
|---|--|
| Preheat | |
| - Temperature Minimum (T _s MIN) | N/A |
| - Temperature Typical (T _s TYP) | 150°C |
| - Temperature Maximum (T _s MAX) | N/A |
| - Time (t _s MIN) | 60 - 120 Seconds |
| Ramp-up Rate (T⊾ to T _P) | 5°C/second Maximum |
| Time Maintained Above: | |
| - Temperature (T∟) | 150°C |
| - Time (t∟) | 200 Seconds Maximum |
| Peak Temperature (T _P) | 240°C Maximum |
| Target Peak Temperature (T _P Target) | 240°C Maximum 1 Time / 230°C Maximum 2 Times |
| Time within 5°C of actual peak (t_p) | 10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time |
| Ramp-down Rate | 5°C/second Maximum |
| Time 25°C to Peak Temperature (t) | N/A |
| Moisture Sensitivity Level | Level 1 |

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.